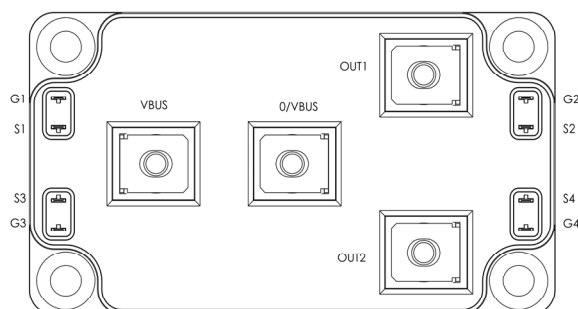
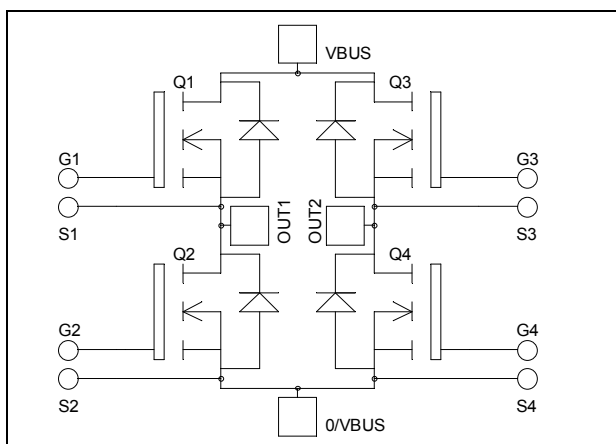


## Full - Bridge MOSFET Power Module

$$V_{DSS} = 1000V$$

$$R_{DSon} = 180m\Omega \text{ typ @ } T_j = 25^\circ C$$

$$I_D = 43A \text{ @ } T_c = 25^\circ C$$



### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

### Features

- Power MOS 7<sup>®</sup> FREDFETs
  - Low  $R_{DSon}$
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{DSS}$	Drain - Source Breakdown Voltage	1000	V
$I_D$	Continuous Drain Current	$T_c = 25^\circ C$	A
		$T_c = 80^\circ C$	
$I_{DM}$	Pulsed Drain current	172	
$V_{GS}$	Gate - Source Voltage	$\pm 30$	V
$R_{DSon}$	Drain - Source ON Resistance	210	m $\Omega$
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)	25	A
$E_{AR}$	Repetitive Avalanche Energy	50	mJ
$E_{AS}$	Single Pulse Avalanche Energy	3000	

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

**All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified**

### Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$ $T_j = 25^\circ\text{C}$			200	$\mu\text{A}$
		$V_{GS} = 0V, V_{DS} = 800V$ $T_j = 125^\circ\text{C}$			1000	
$R_{DS(on)}$	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 21.5A$		180	210	$m\Omega$
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$	3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30V, V_{DS} = 0V$			$\pm 150$	nA

### Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$ $V_{DS} = 25V$ $f = 1MHz$		10.4		nF
$C_{oss}$	Output Capacitance			1.76		
$C_{rss}$	Reverse Transfer Capacitance			0.32		
$Q_g$	Total gate Charge	$V_{GS} = 10V$ $V_{Bus} = 500V$ $I_D = 43A$		372		nC
$Q_{gs}$	Gate – Source Charge			48		
$Q_{gd}$	Gate – Drain Charge			244		
$T_{d(on)}$	Turn-on Delay Time	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V$ $V_{Bus} = 670V$ $I_D = 43A$ $R_G = 2.5\Omega$		18		ns
$T_r$	Rise Time			12		
$T_{d(off)}$	Turn-off Delay Time			155		
$T_f$	Fall Time			40		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>25^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 43A, R_G = 2.5\Omega$		1800		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			1246		
$E_{on}$	Turn-on Switching Energy	<b>Inductive switching @ <math>125^\circ\text{C}</math></b> $V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 43A, R_G = 2.5\Omega$		2846		$\mu\text{J}$
$E_{off}$	Turn-off Switching Energy			1558		

### Source - Drain diode ratings and characteristics

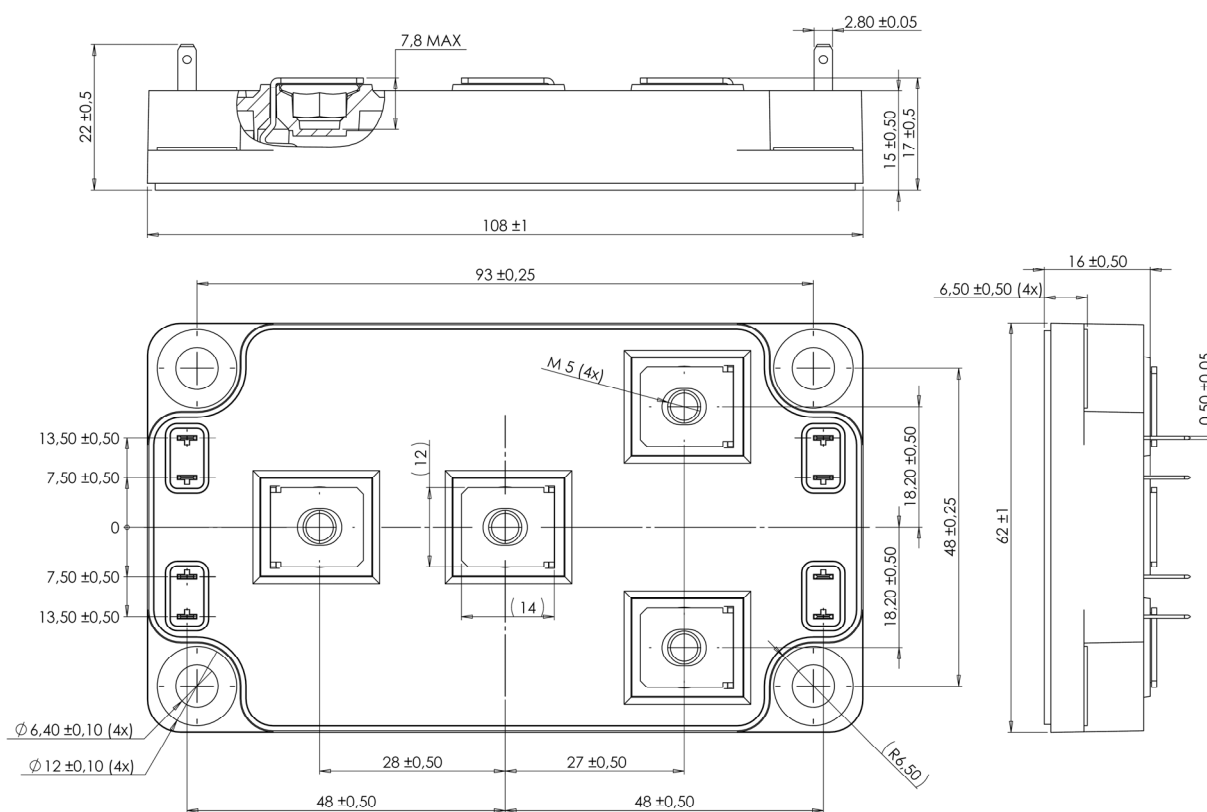
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_S$	Continuous Source current (Body diode)	$T_c = 25^\circ\text{C}$			43	A
		$T_c = 80^\circ\text{C}$			33	
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -43A$			1.3	V
$dv/dt$	Peak Diode Recovery ①				18	V/ns
$t_{rr}$	Reverse Recovery Time	$I_S = -43A$ $V_R = 670V$ $di/dt = 200A/\mu s$	$T_j = 25^\circ\text{C}$		320	ns
			$T_j = 125^\circ\text{C}$		650	
$Q_{rr}$	Reverse Recovery Charge	$I_S = -43A$ $V_R = 670V$ $di/dt = 200A/\mu s$	$T_j = 25^\circ\text{C}$	7.2		$\mu\text{C}$
			$T_j = 125^\circ\text{C}$	19.5		

①  $dv/dt$  numbers reflect the limitations of the circuit rather than the device itself.

$I_S \leq -43A$      $di/dt \leq 700A/\mu s$      $V_R \leq V_{DSS}$      $T_j \leq 150^\circ\text{C}$

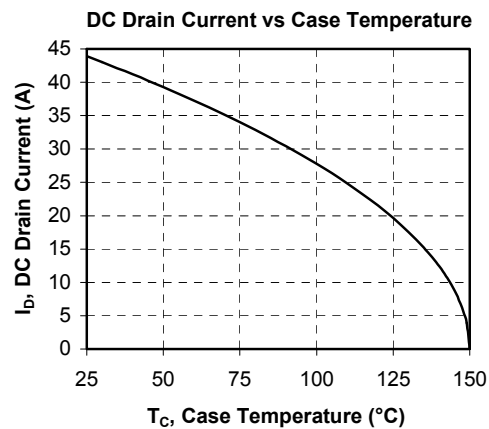
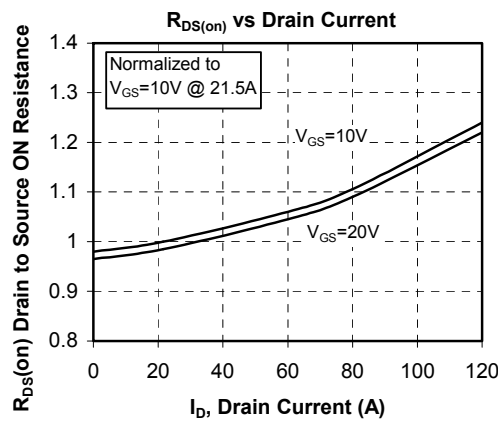
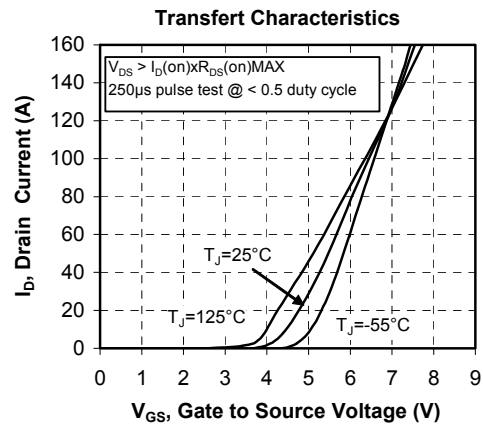
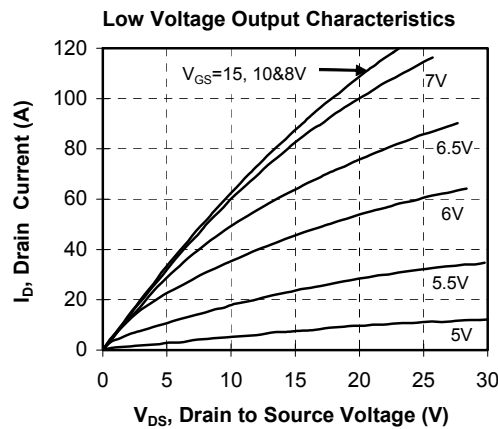
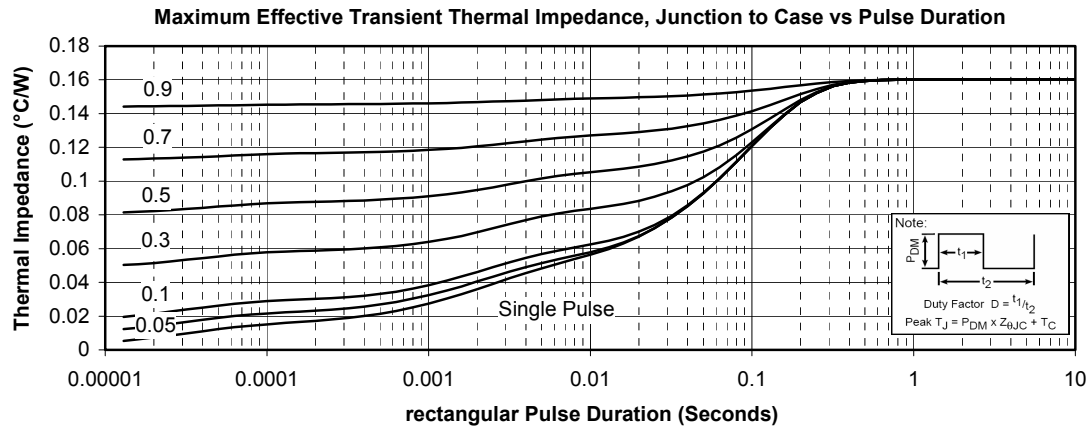
**Thermal and package characteristics**

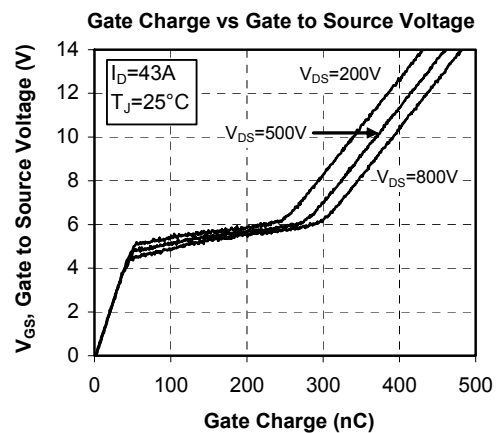
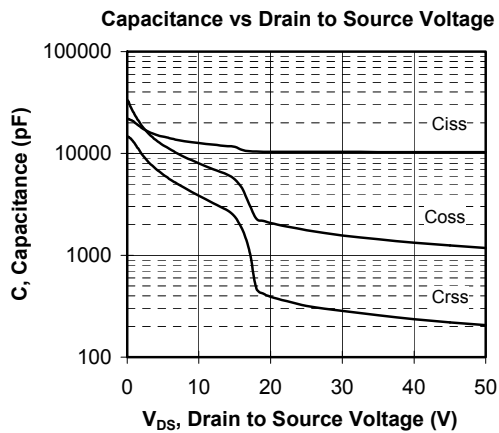
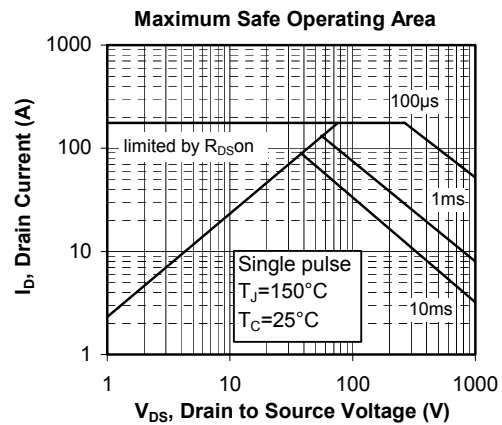
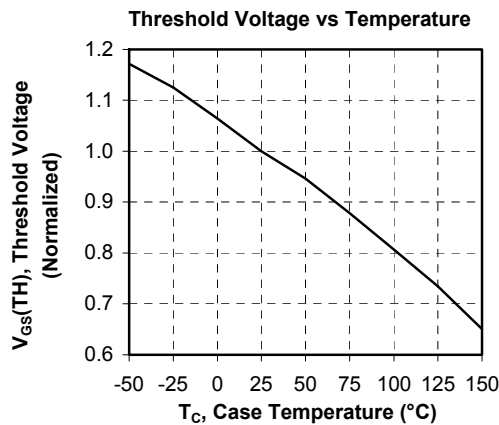
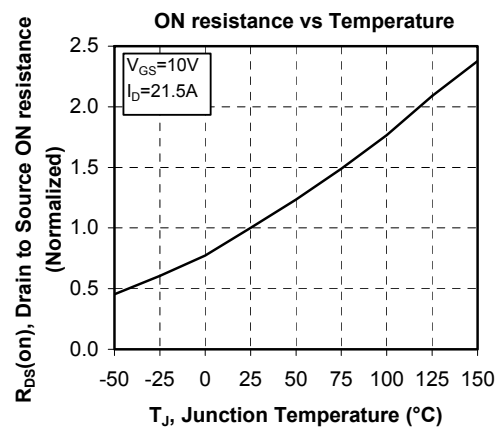
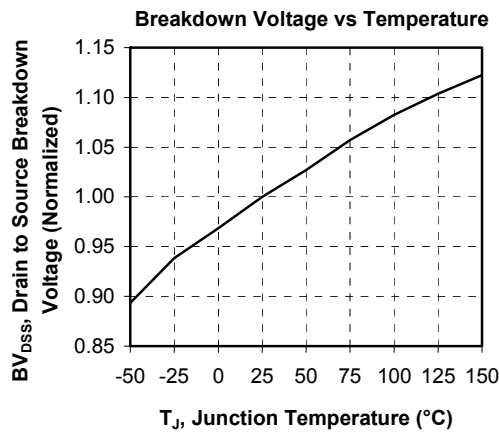
Symbol	Characteristic	Min	Typ	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance			0.16	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz	4000			V
$T_J$	Operating junction temperature range	-40		150	°C
$T_{STG}$	Storage Temperature Range	-40		125	
$T_C$	Operating Case Temperature	-40		100	
Torque	Mounting torque	To heatsink	M6	3	N.m
		For terminals	M5	2	
Wt	Package Weight			300	g

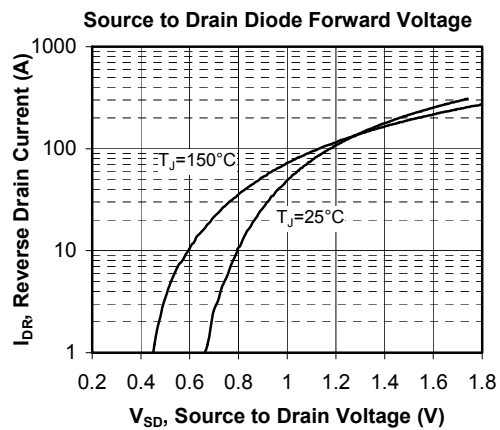
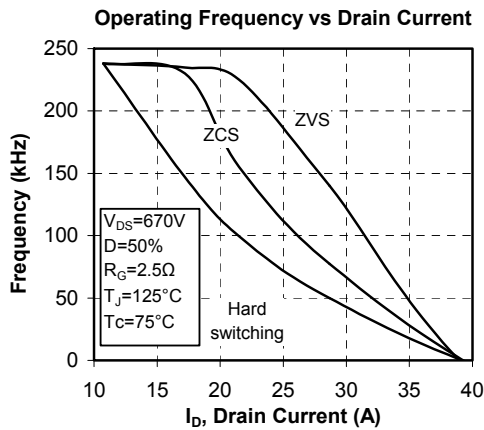
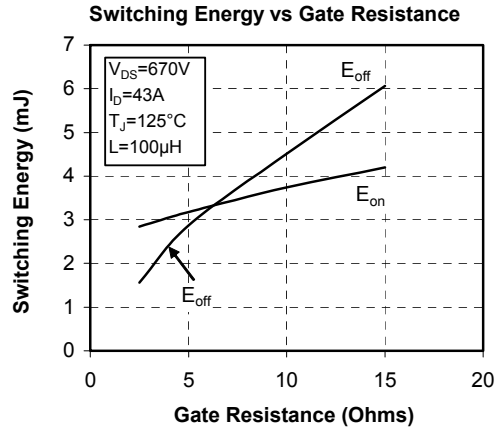
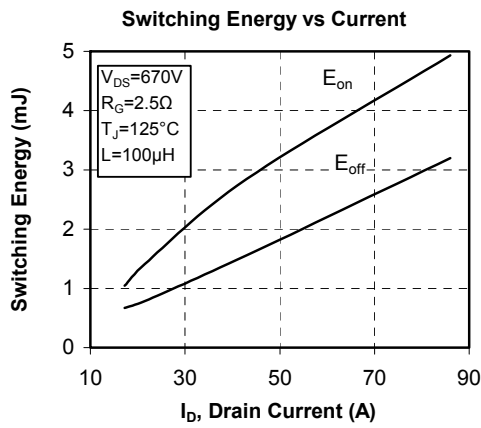
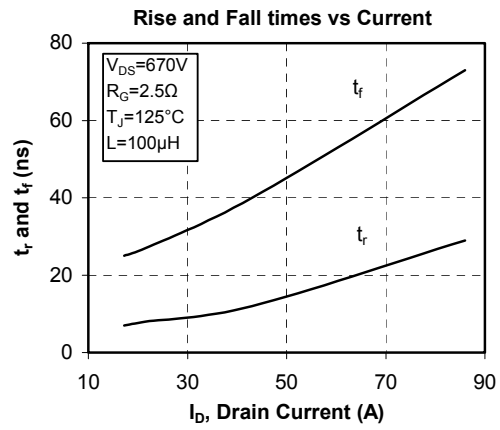
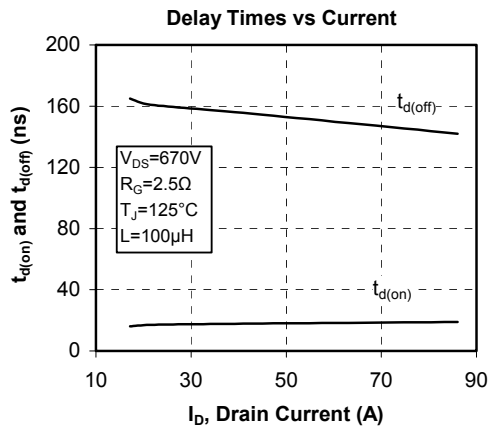
**SP6 Package outline (dimensions in mm)**


See application note APT0601 - Mounting Instructions for SP6 Power Modules on [www.microsemi.com](http://www.microsemi.com)

## Typical Performance Curve







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